

# 54LS00/DM54LS00/DM74LS00 Quad 2-Input NAND Gates

#### **General Description**

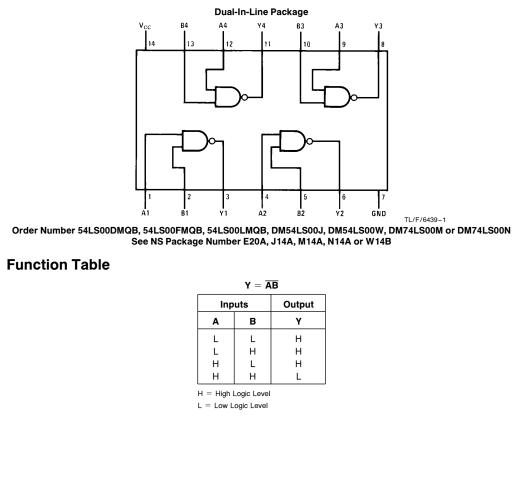
#### Features

This device contains four independent gates each of which performs the logic NAND function.

 Alternate Military/Aerospace device (54LS00) is available. Contact a National Semiconductor Sales Office/ Distributor for specifications. 54LS00/DM54LS00/DM74LS00 Quad 2-Input NAND Gates

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### **Connection Diagram**



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#### Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	7V
Input Voltage	7V
Operating Free Air Temperature Range	
DM54LS and 54LS	-55°C to +125°C
DM74LS	$0^{\circ}C$ to $+70^{\circ}C$
Storage Temperature Range	-65°C to +150°C

Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

### **Recommended Operating Conditions**

Symbol	Parameter	DM54LS00			DM74LS00			Units
		Min	Nom	Max	Min	Nom	Max	Onito
V <sub>CC</sub>	Supply Voltage	4.5	5	5.5	4.75	5	5.25	V
V <sub>IH</sub>	High Level Input Voltage	2			2			V
V <sub>IL</sub>	Low Level Input Voltage			0.7			0.8	V
I <sub>OH</sub>	High Level Output Current			-0.4			-0.4	mA
I <sub>OL</sub>	Low Level Output Current			4			8	mA
T <sub>A</sub>	Free Air Operating Temperature	-55		125	0		70	°C

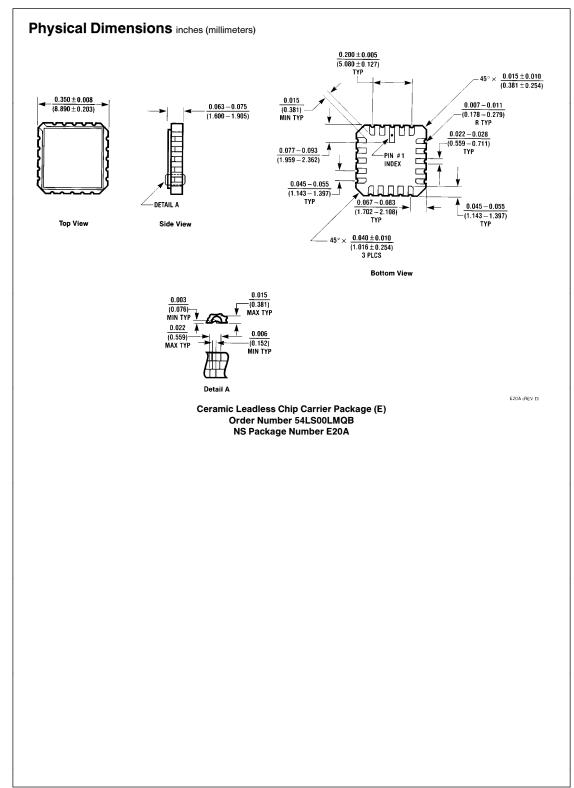
### Electrical Characteristics over recommended operating free air temperature range (unless otherwise noted)

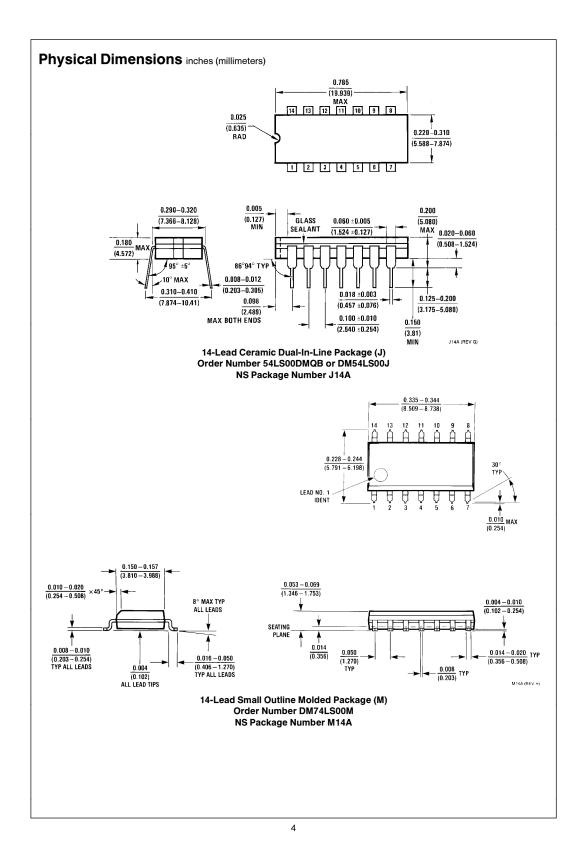
Symbol	Parameter	Conditions		Min	Typ (Note 1)	<b>Max</b> - 1.5	Units V
VI	Input Clamp Voltage	$V_{CC} = Min, I_I = -18 \text{ mA}$	= -18 mA				
0.1	High Level Output	$V_{CC} = Min, I_{OH} = Max, V_{IL} = Max$	DM54	2.5	3.4		v
	Voltage		DM74	2.7	3.4		
V <sub>OL</sub> Low Level Output Voltage	$V_{CC} = Min, I_{OL} = Max,$	DM54		0.25	0.4		
	Voltage V <sub>IH</sub> = Min	DM74		0.35	0.5	v	
		$I_{OL} = 4 \text{ mA}, V_{CC} = \text{Min}$	DM74		0.25	0.4	1
I	Input Current @ Max Input Voltage	$V_{CC} = Max, V_I = 7V$				0.1	mA
IIH	High Level Input Current	$V_{CC} = Max, V_I = 2.7V$				20	μA
IIL	Low Level Input Current	$V_{CC} = Max, V_I = 0.4V$				-0.36	mA
00	Short Circuit	V <sub>CC</sub> = Max (Note 2)	DM54	-20		-100	- mA
	Output Current		DM74	-20		-100	
Іссн	Supply Current with Outputs High	V <sub>CC</sub> = Max			0.8	1.6	mA
ICCL	Supply Current with Outputs Low	V <sub>CC</sub> = Max			2.4	4.4	mA

## Switching Characteristics at $V_{CC} = 5V$ and $T_A = 25^{\circ}C$ (See Section 1 for Test Waveforms and Output Load)

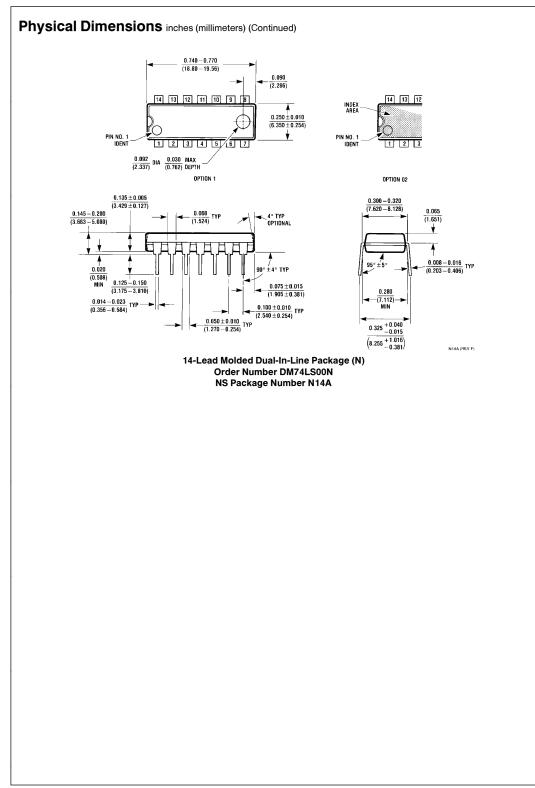
	Parameter	$R_L = 2 k\Omega$					
Symbol		C <sub>L</sub> =	15 pF	$C_L = 50  pF$		Units	
		Min	Max	Min	Мах		
t <sub>PLH</sub>	Propagation Delay Time Low to High Level Output	3	10	4	15	ns	
t <sub>PHL</sub>	Propagation Delay Time High to Low Level Output	3	10	4	15	ns	
Note 1: All typicals are at $V_{CC} = 5V$ , $T_A = 25^{\circ}C$ .							

Note 2: Not more than one output should be shorted at a time, and the duration should not exceed one second.

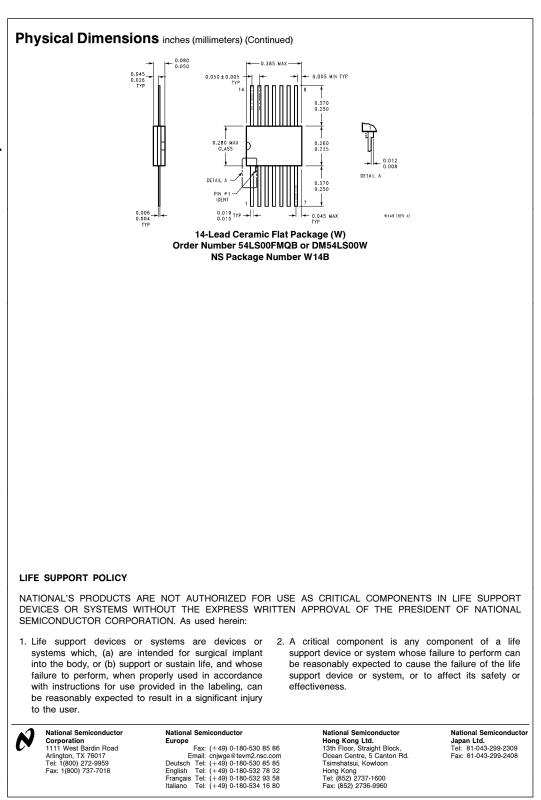




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5



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